

Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>		<i>Complete if Known</i>	
		Application Number	10/081,818
		Filing Date	February 20, 2002
		First Named Inventor	Eldridge, Jerome
		Group Art Unit	2818
		Examiner Name	Ho, Tu-Tu
Sheet 1 of 1		Attorney Docket No: 1303.045US1	

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Examiner Initials*	Cite No ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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EXAMINER /Tu Tu Ho/ (12/15/2006) DATE CONSIDERED 12/15/2006